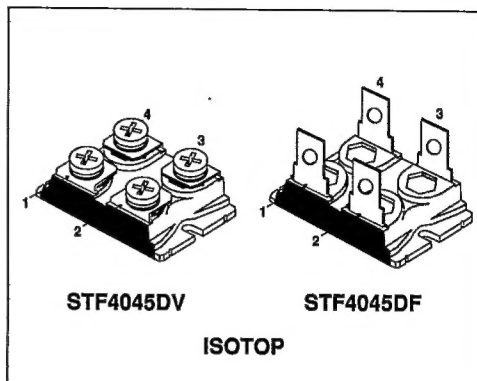


NPN DARLINGTON POWER MODULE

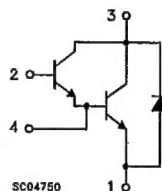
- EASY TO DRIVE TECHNOLOGY (ETD)
- HIGH CURRENT POWER BIPOLAR
- MODULE VERY LOW R_{th} JUNCTION CASE
- SPECIFIED ACCIDENTAL OVERLOAD AREAS
- ULTRAFAST FREEWHEELING DIODE
- ISOLATED CASE (2500V RMS)
- EASY TO MOUNT
- LOW INTERNAL PARASITIC INDUCTANCE

INDUSTRIAL APPLICATIONS:

- MOTOR CONTROL
- SMPS & UPS
- WELDING EQUIPMENT



INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CEV}	Collector-Emitter Voltage ($V_{BE} = -5$ V)	600	V
$V_{CEO(sus)}$	Collector-Emitter Voltage ($I_B = 0$)	450	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	7	V
I_C	Collector Current	42	A
I_{CM}	Collector Peak Current ($t_p = 10$ ms)	63	A
I_B	Base Current	4	A
I_{BM}	Base Peak Current ($t_p = 10$ ms)	8	A
P_{tot}	Total Dissipation at $T_c = 25$ °C	150	W
T_{stg}	Storage Temperature	-55 to 150	°C
T_J	Max. Operating Junction Temperature	150	°C
V_{iso}	Insulation Withstand Voltage (AC-RMS)	2500	V

THERMAL DATA

T-33-35

R _{thj-case}	Thermal Resistance Junction-case (transistor)	Max	0.83	°C/W
R _{thj-case}	Thermal Resistance Junction-case (diode)	Max	1.5	°C/W
R _{thc-h}	Thermal Resistance Case-heatsink With Conductive Grease Applied	Max	0.05	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CEr} #	Collector Cut-off Current (R _{BE} = 5 Ω)	V _{CE} = V _{CEV} V _{CE} = V _{CEV} T _J = 100 °C			1 7	mA mA
I _{CEV} #	Collector Cut-off Current (V _{BE} = -5)	V _{CE} = V _{CEV} V _{CE} = V _{CEV} T _J = 100 °C			1 7	mA mA
I _{EB0} #	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			1	mA
V _{CE0(sus)} *	Collector-Emitter Sustaining Voltage	I _C = 0.2 A L = 25 mH V _{olamp} = 450 V	450			V
h _{FE} *	DC Current Gain	I _C = 35 A V _{CE} = 5 V		300		
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = 25 A I _B = 0.5 A I _C = 25 A I _B = 0.5 A T _J = 100 °C I _C = 35 A I _B = 2 A I _C = 35 A I _B = 2 A T _J = 100 °C		1.2 1.3 1.4 1.4	2 2	V V V V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	I _C = 35 A I _B = 2 A I _C = 35 A I _B = 2 A T _J = 100 °C		2.3 2.3	3	V V
dI _C /dt	Rate of Rise of On-state Collector	V _{CC} = 300 V R _C = 0 t _p = 3 μs I _{B1} = 0.75 A T _J = 100 °C	200			A/μs
V _{CE(3 μs)}	Collector-Emitter Dynamic Voltage	V _{CC} = 300 V R _C = 12 Ω I _{B1} = 0.75 A T _J = 100 °C		2	4	V
V _{CE(5 μs)}	Collector-Emitter Dynamic Voltage	V _{CC} = 300 V R _C = 12 Ω I _{B1} = 0.75 A T _J = 100 °C		1.6	3	V
t _s	Storage Time	I _C = 25 A V _{CC} = 50 V		3	4.5	μs
t _f	Fall Time	V _{BB} = -5 V R _{BB} = 0.6 Ω		0.1	0.3	μs
t _c	Cross-over Time	V _{olamp} = 450 V I _{B1} = 0.5 A L = 0.1 mH T _J = 100 °C		0.3	1	μs
t _s	Storage Time	I _C = 25 A V _{CC} = 50 V		5.4		μs
t _f	Fall Time	V _{BB} = 0 V R _{BB} = 0.6 Ω		0.22		μs
t _c	Cross-over Time	V _{olamp} = 450 V I _{B1} = 0.5 A L = 0.1 mH T _J = 100 °C		0.6		μs
V _{CEW}	Maximum Collector Emitter Voltage Without Snubber	I _{CWoff} = 42 A I _{B1} = 2 A V _{BB} = -5 V V _{CC} = 50 V L = 60 μH R _{BB} = 0.6 Ω T _J = 125 °C	400			V
V _F *	Diode Forward Voltage	I _F = 35 A T _J = 100 °C			1.85	V
I _{RM}	Reverse Recovery Current	V _{CC} = 200 V I _F = 35 A dI _F /dt = -200 A/μs L < 0.05 μH T _J = 100 °C			24	A

* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

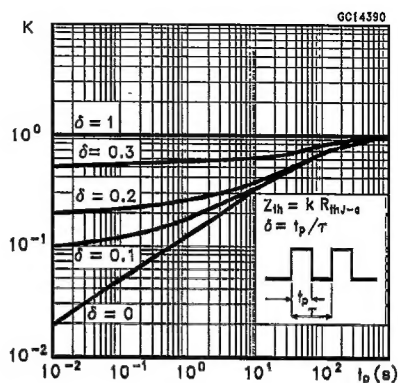
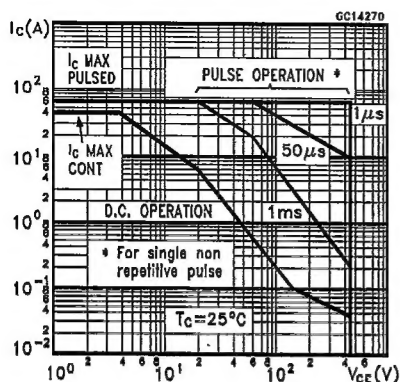
See test circuits in databook introduction

To evaluate the conduction losses of the diode use the following equations:

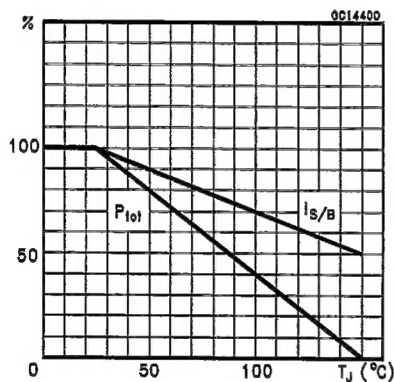
$$V_F = 1.1 + 0.007 I_F \quad P = 1.1 I_F(V_F) + 0.007 I_F^2 R_{(RMS)}$$

Safe Operating Areas

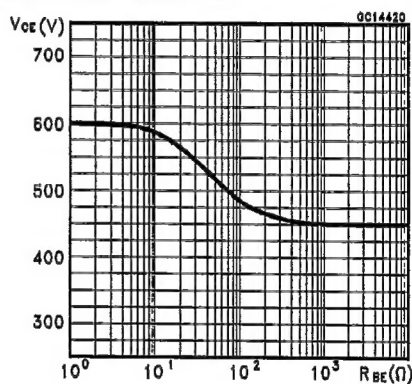
Thermal Impedance



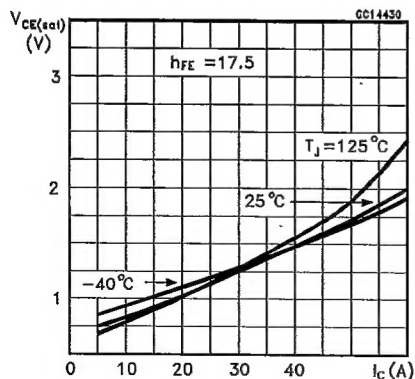
Derating Curve



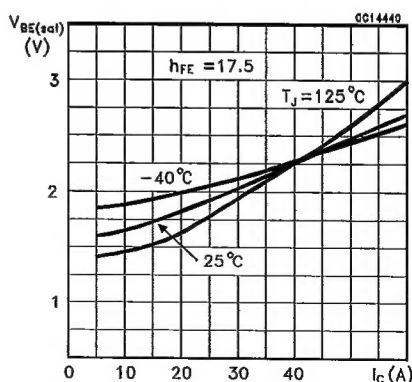
Collector-Emitter Voltage Versus Base-Emitter Resistance



Collector-Emitter Saturation Voltage

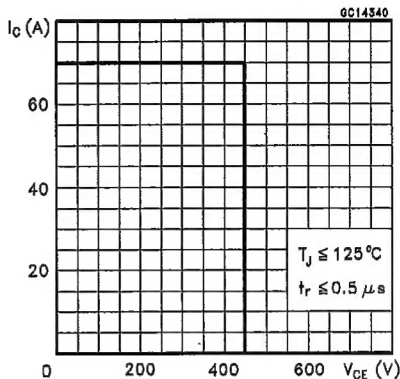
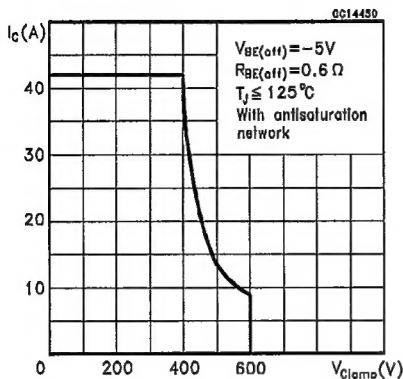


Base-Emitter Saturation Voltage



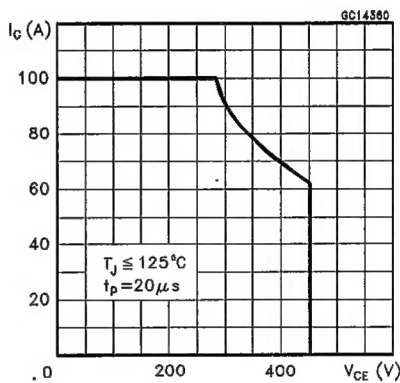
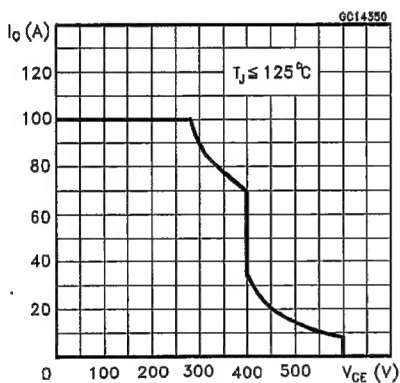
Reverse Biased SOA

Forward Biased SOA



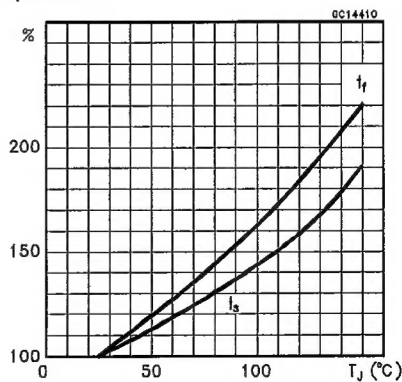
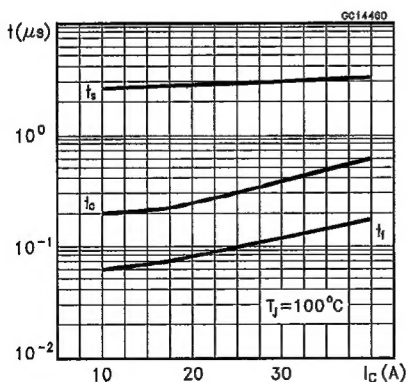
Reverse Biased AOA

Forward Biased AOA

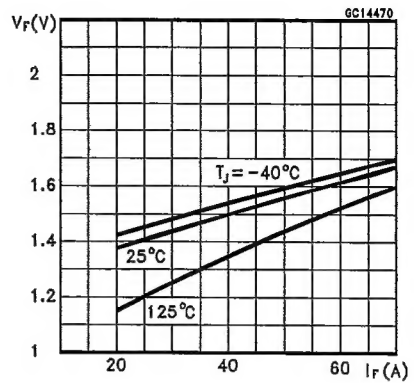
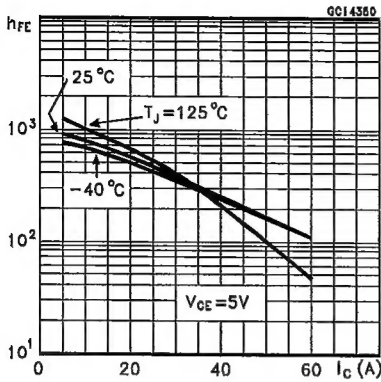


Switching Times Inductive Load

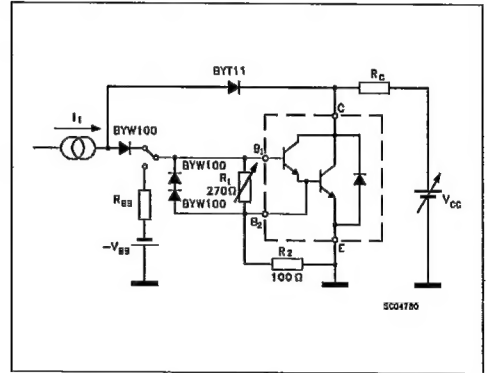
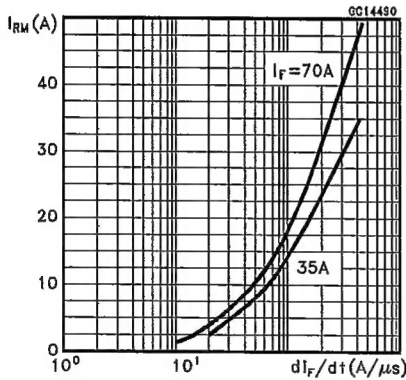
Switching Times Inductive Load Versus Temperature



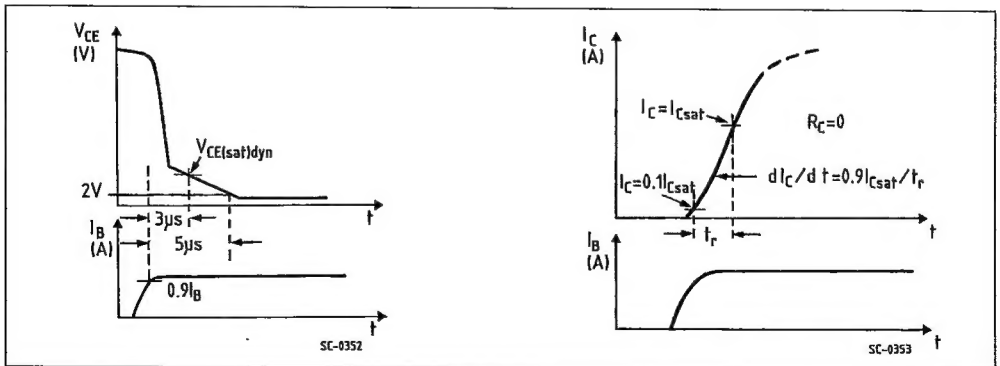
DC Current Gain

Typical V_F Versus I_F Peak Reverse Current Versus di_F/dt

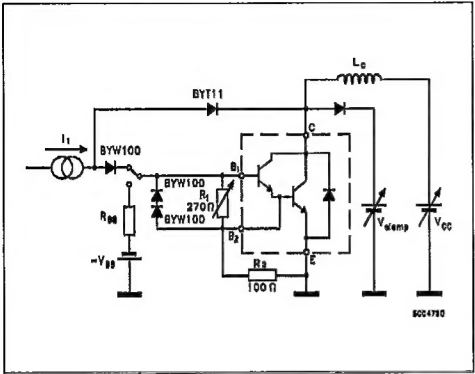
Turn-on Switching Test Circuit



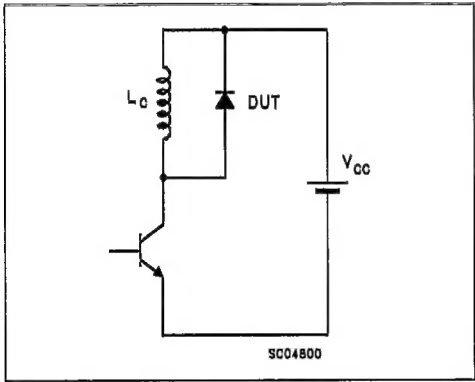
Turn-on Switching Waveforms



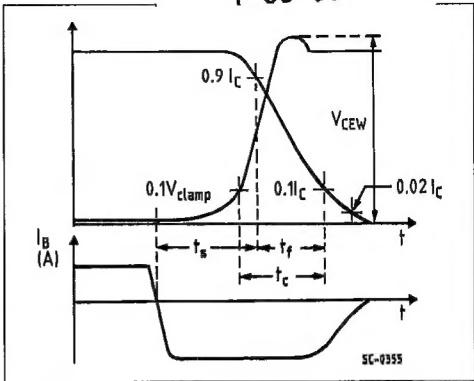
Turn-off Switching Test Circuit



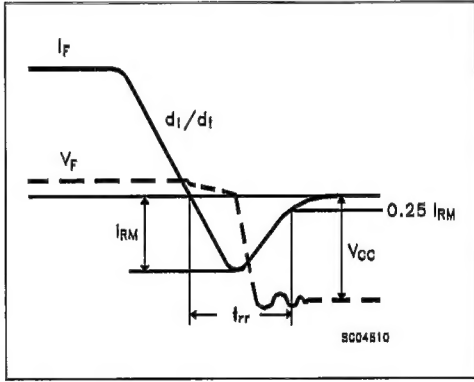
Turn-off Switching Test Circuits of Diode



Turn-off Switching Waveforms

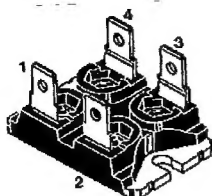


Turn-off Switching Waveform of Diode

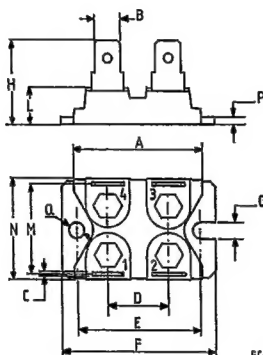


S G S-THOMSON

T-91-20



ISOTOP
Fast-on version
sales types with the suffix F

MECHANICAL DATA

FC-9309

	DIMENSIONS			
	mm		Inches	
	min.	max	min.	max
A	31.5	31.7	1.240	1.248
B	6.2	6.4	0.244	0.252
C	0.75	0.85	0.029	0.033
D	14.9	15.1	0.586	0.590
E	30.1	30.3	1.185	1.193
F	38	38.2	1.496	1.503
G	4	—	0.157	—
H	20.3	20.7	0.799	0.815
L	8.9	9.1	0.350	0.358
M	22.4	23	0.881	0.905
N	25.2	25.4	0.992	1.000
P	1.95	2.05	0.076	0.080
Q	4	—	0.157	—

PIN CONNECTIONS**MOSFET**

pin 1: Source pin 2: Gate
pin 3: Drain pin 4: Source sensing

DARLINGTON

pin 1: Emitter pin 2: Base1
pin 3: Collector pin 4: Base 2

TRANSISTOR

pin 1: Emitter pin 2: Base
pin 3: Collector pin 4: Emitter sensing

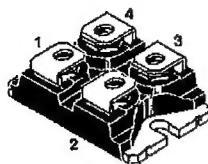
Torque: Mounting $1.3 \pm 0.2 \text{ N} \cdot \text{m}$ (max)

Weight: Package 25.5 g

Note: The mechanical data are the same for the 3 pin version
(4th pin missing)

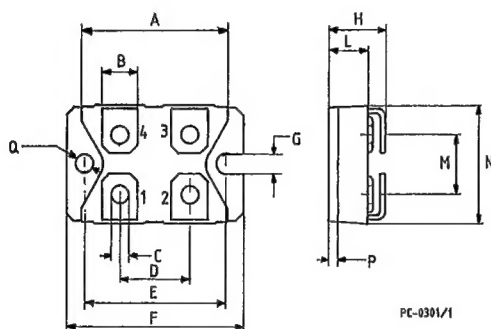
S G S-THOMSON

T-91-20



ISOTOP
Screw version
sales types with the suffix V

MECHANICAL DATA



PC-0301/1

	DIMENSIONS			
	mm		Inches	
	min.	max	min.	max
A	31.5	31.7	1.240	1.248
B	7.8	8.2	0.307	0.322
C	4.1	4.3	0.161	0.169
D	14.9	15.1	0.586	0.590
E	30.1	30.3	1.185	1.193
F	38	38.2	1.496	1.503
G	4	—	0.157	—
H	11.8	12.2	0.464	0.480
L	8.9	9.1	0.350	0.358
M	12.6	12.8	0.496	0.503
N	25.2	25.4	0.992	1.000
P	1.95	2.05	0.076	0.080
Q	4	—	0.157	—

PIN CONNECTIONS

MOSFET

pin 1: Source pin 2: Gate
pin 3: Drain pin 4: Source sensings

DARLINGTON

pin 1: Emitter pin 2: Base1
pin 3: Collector pin 4: Base 2

TRANSISTOR

pin 1: Emitter pin 2: Base
pin 3: Collector pin 4: Emitter sensing

Torque: Terminal $1.3 \pm 0.2 \text{ N} \cdot \text{m}$ (max)
Mounting $1.3 \pm 0.2 \text{ N} \cdot \text{m}$ (max)

Weight: Package 29 g
4 Screws: 7.5 g

Note: The mechanical data are the same for the 3 pin version
(4th pin missing)

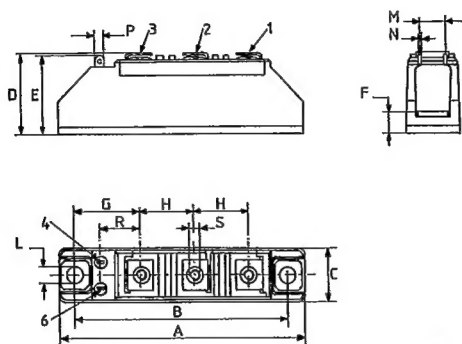
S G S-THOMSON

T-91-20

TRANSPACK (TO-240)



MECHANICAL DATA



PC-0296

Torque: Terminal $2.2 \pm 0.5 \text{ N} \cdot \text{m}$ (max)
 Mounting $3.5 \pm 0.5 \text{ N} \cdot \text{m}$ (max)

Weight: Package 110 g
 Accessory 21 g

Note: The mechanical data are the same for the 2 power pin version (either pin 1 or pin 2 missing)

	DIMENSIONS			
	mm		Inches	
	min.	max	min.	max
A	91.5	92.5	3.602	3.641
B	79.75	80.25	3.140	3.160
C	19.5	20.55	0.767	0.809
D	29.00	31.00	1.141	1.220
E	28.8	30	1.134	1.181
F	8.5 typ.		0.334 typ.	
G	24.4 typ.		0.960 typ.	
H	19.5	20.5	0.767	0.807
L	6.2 typ.		0.244 typ.	
M	8.95	11.05	0.352	0.435
N	0.78	0.84	0.030	0.033
P	2.72	2.87	0.107	0.113
R	14	—	0.551	—
S	M5			